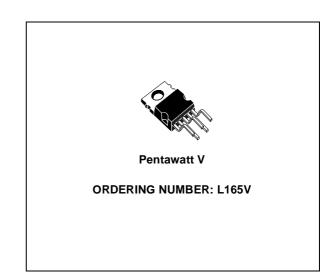


3A POWER OPERATIONAL AMPLIFIER

- OUTPUT CURRENT UP TO 3A
- LARGE COMMON-MODE AND DIFFERENTIAL MODE RANGES
- SOA PROTECTION
- THERMAL PROTECTION
- ± 18V SUPPLY

DESCRIPTION

The L165 is a monolithic integrated circuit in Pentawatt® package, intended for use as power operational amplifier in a wide range of applications, including servo amplifiers and power supplies. The high gain and high output power capability provide superiore performance wherever an operational amplifier/power booster combination is required.



APPLICATION CIRCUITS

Figure 1. Gain > 10.

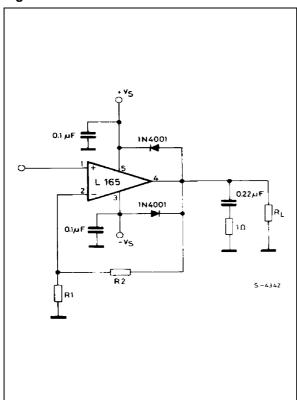
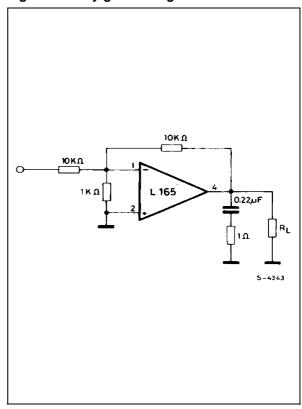


Figure 2. Unity gain configuration.

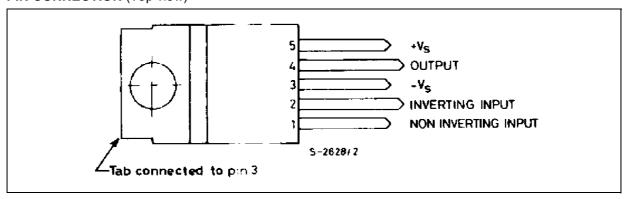


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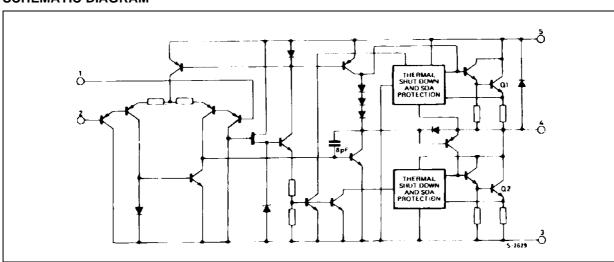
ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
Vs	Supply voltage	± 18	V
V ₅ V ₄	Upper power transistor V _{CE}	36	V
V ₄ V ₃	Lower power transistor V _{CE}	36	V
Vi	Input voltage	Vs	
Vj	Differential input voltage	± 15	V
lo	Peak output current (internally limited)	3.5	Α
P _{tot}	Power dissipation at T _{case} = 90°C	20	W
T _{stg} , T _j	Storage and junction temperature	-40 to 150	°C

PIN CONNECTION (Top view)



SCHEMATIC DIAGRAM



THERMAL DATA

Symbol	Parameter	Value	Unit
R _{th-j-case}	Thermal resistance junction-case max	3	°C/W

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ELECTRICAL CHARACTERISTCS ($V_S = \pm 15 \text{ V}, T_j = 25 \text{ °C}$ unless otherwise specified)

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
Vs	Supply Voltage		± 6		± 18	V
l _d	Quiescent Drain Current	V _S = ±18 V		40	60	mA
lb	Input Bias Current			0.2	1	μΑ
Vos	Input Offset Voltage			± 2	± 10	mV
I _{os}	Input Offset Current			± 20	± 200	nA
SR	Slew-rate	G _v = 10	8			V/μs
		G _v = 1 (°)	6			
Vo	Output Voltage Swing	f = 1kHz lp = 0.3A lp = 3A		27 24		Vpp
		f = 10kHz Ip = 0.3A Ip = 3A		27 24		Vpp
R	Input Resistance (pin 1)	f = 1 KHz	100	500		ΚΩ
Gv	Voltage Gain (open loop)			80		dB
e _N	Input Noise Voltage	B = 10 to 10 000 Hz		2		μV
ⁱ N	Input Noise Current	f = 1 KHz		100		pА
CMR	Common-mode Rejection	$R_g \le 10 \text{ K}\Omega; G_V = 30 \text{ dB}$		70		dB
SVR	Supply Voltage Rejection	$R_g = 22 \text{ K}\Omega; \text{ V_{ripple} = 0.5 Vrms} \\ f_{ripple} = 100 \text{ Hz} \\ G_V = 10 \\ G_V = 100 \\ G_V $		60 40		dB dB
	Efficiency	$f = 1 \text{ kHz}; R_L = 4\Omega$ $I_p = 1.6 \text{ A}; P_0 = 5W$ $I_p = 1.6 \text{ A}; P_0 = 18W$		70 60		% %
^T sd	Thermal Shut-down Case	$P_{tot} = 12 W$	-	110		°C
	Temperature	$P_{tot} = 6 W$		130		°C

Figure 3. Open loop frequency response.

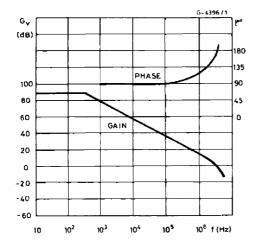


Figure 4. Closed loop frequency response (circuit of figure 2).

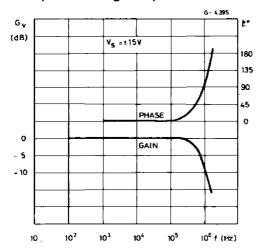


Figure 5. Large signal frequency response.

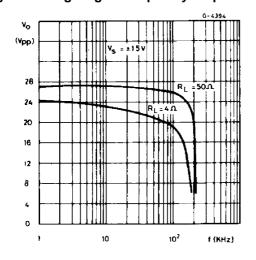


Figure 6. Maximum output current vs. voltage [VCE] across each output transistor.

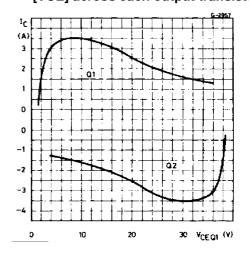


Figure 7. Safe operating area and collector characteristics of the protected power transistor.

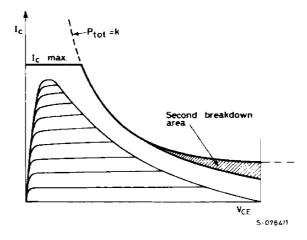
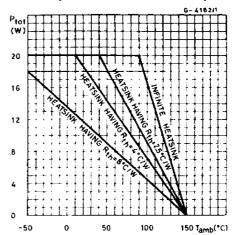


Figure 8. Maximum allowable power dissipation vs. ambient temperature.



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Figure 9. Bidirectional DC motor control with TTL/CMOS/ μ P compatible inputs.

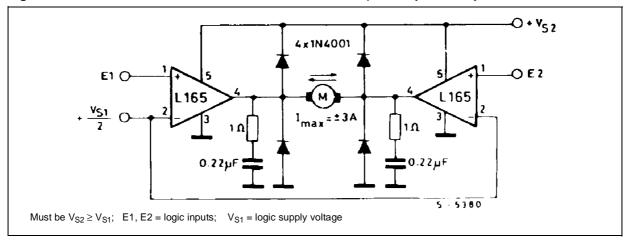


Figure 10. Motor current control circuit with external power transistors ($I_{motor} > 3.5A$).

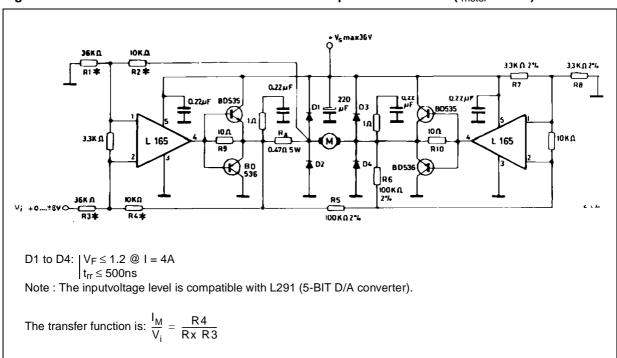


Figure 11. High current tracking regulator.

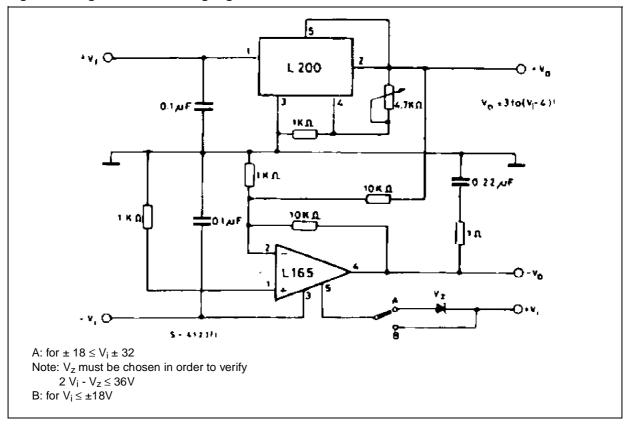
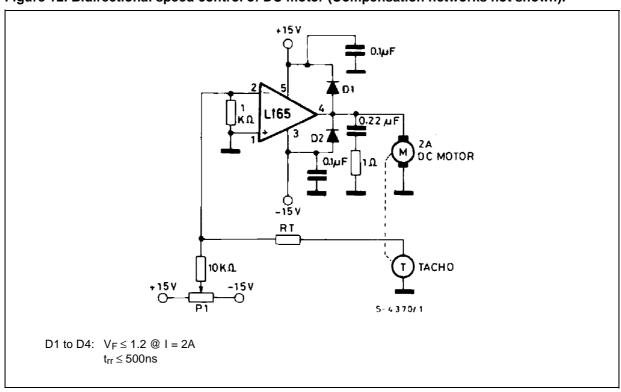


Figure 12. Bidirectional speed control of DC motor (Compensation networks not shown).



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Figure 13. Split power supply.

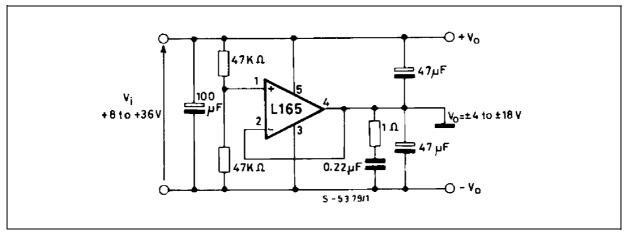
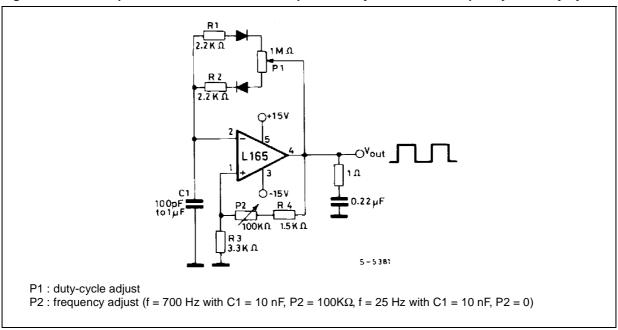
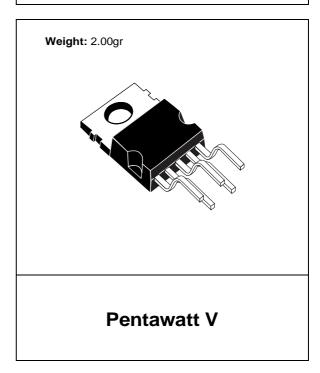


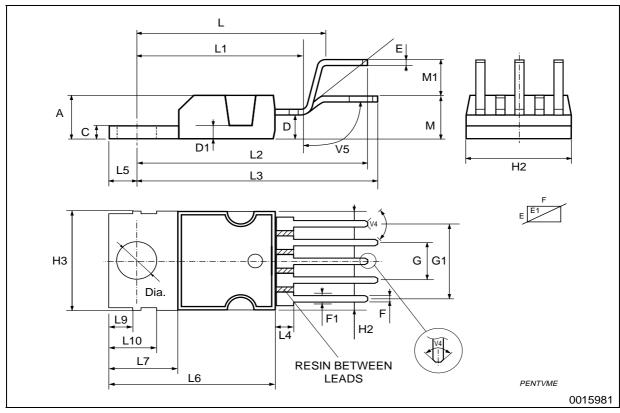
Figure 14. Power squarewave oscillator with independent adjustments for frequency and duty-cycle.



		mm			inch	
DIM.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
Α			4.8			0.189
С			1.37			0.054
D	2.4		2.8	0.094		0.110
D1	1.2		1.35	0.047		0.053
Е	0.35		0.55	0.014		0.022
E1	0.76		1.19	0.030		0.047
F	0.8		1.05	0.031		0.041
F1	1.0		1.4	0.039		0.055
G	3.2	3.4	3.6	0.126	0.134	0.142
G1	6.6	6.8	7.0	0.260	0.268	0.276
H2			10.4			0.409
Н3	10.05		10.4	0.396		0.409
L	17.55	17.85	18.15	0.691	0.703	0.715
L1	15.55	15.75	15.95	0.612	0.620	0.628
L2	21.2	21.4	21.6	0.831	0.843	0.850
L3	22.3	22.5	22.7	0.878	0.886	0.894
L4			1.29			0.051
L5	2.6		3.0	0.102		0.118
L6	15.1		15.8	0.594		0.622
L7	6.0		6.6	0.236		0.260
L9	2.1		2.7	0.008		0.106
L10	4.3		4.8	0.17		0.189
М	4.23	4.5	4.75	0.167	0.178	0.187
M1	3.75	4.0	4.25	0.148	0.157	0.167
V4	40° (typ.)					
V5	90° (typ.)					
Dia	3.65		3.85	0.144		0.152

OUTLINE AND MECHANICAL DATA





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